Nanostructured composites of semiconductor metal 6<sup>th</sup> NANO oxides with noble metals (Au, Pt): comparison of Boston sensitivity to volatile organic compounds Conference (Virtual) Artem Marikutsa

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## Introduction

Metal oxide semiconductors (MOS) functionalized by catalytic noble metals are promising for gas sensors of volatile organic compounds (VOC). However, the relations of materials composition and sensing behavior is unclear. In this work, we compare the sensitivity and selectivity of different MOS and composites MOS/Au, MOS/Pt to methanol and acetone. Nanoparticles of p-type (NiO, CuO, Co<sub>3</sub>O<sub>4</sub>) and n-type (In<sub>2</sub>O<sub>3</sub>, ZnO, SnO<sub>2</sub>, TiO<sub>2</sub>, and WO<sub>3</sub>) MOS were obtained by conventional aqueous deposition method. Active sites (surface oxygen species and acid sites) were analyzed. Metal-oxygen bond energy (E<sub>M-O</sub>) was chosen as a descriptor for the observed difference in active sites concentration and gas sensitivity. The interaction routes of methanol and acetone with materials surfaces were examined by diffuse-reflectance infrared spectroscopy (DRIFT). Oxidation of methanol and acetone to CO, formate and acetate species was revealed, roles of active sites in these reactions were rationalized.



	MOS	Туре	E <sub>M-O</sub> , eV	Band gap, eV	Grain size, nm	BET area, m²/g
	NiO	p-type	4.8	3.5	7	110
	CuO		7.1	1.6	15	30
	Co <sub>3</sub> O <sub>4</sub>		9.3	1.5	12	70
	In <sub>2</sub> O <sub>3</sub>	n-type	9.3	2.8	8	105
	ZnO		10.4	3.4	35	10
	SnO <sub>2</sub>		15.5	3.6	5	100
	TiO <sub>2</sub>		20.7	3.2	30-40	8











- $\checkmark$  Surface acidity of MOS increased with the bond energy E<sub>M-O</sub>, the acid sites favor adsorption of VOC molecules CH<sub>3</sub>OH and CH<sub>3</sub>COCH<sub>3</sub>
- $\checkmark$  Sensitivity to VOC followed the volcano-like dependence on E<sub>M-O</sub> for *p*-type MOS-based sensors and *n*-type MOS/Au sensors due to increased concentration of adsorbed oxygen on these materials
- ✓ Sensitivity to VOC increased with E<sub>M-O</sub> for *n*-type MOS/Pt due to Pt-catalyzed conversion of VOC to CO on the acidic metal oxides

 $4 CH_3COCH_3 + 9 O_7 = 4 CH_3COO^2 + 4 CO_7 + 6 H_2O + 9 e^2$ 

 $CH_3COCH_3 + 3Pt + 3O_2 = 3Pt-CO + 3H_2O + 3e^{-1}$ (on acidic MOS)